

# **DATASHEET**

# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER 4N2X Series 4N3X Series H11AX Series



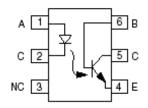




#### Features:

- 4N2X series: 4N25, 4N26, 4N27, 4N28
- 4N3X series: 4N35, 4N36, 4N37, 4N38
- H11AX series: H11A1, H11A2, H11A3, H11A4, H11A5
- High isolation voltage between input and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approval
- DEMKO approval
- FIMKO approval
- CSA approved
- CQC approved

### Schematic



#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base

# **Description**

The 4N2X, 4N3X, H11AX series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

# **Applications**

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs



# Absolute Maximum Ratings (Ta=25℃)

|                         | Parameter                                 | Symbol                      | Rating | Unit  |
|-------------------------|---|-----------------------------|--------|-------|
|                         | Forward current                           | I <sub>F</sub>              | 60     | mA    |
|                         | Peak forward current (t = 10µs)           | I <sub>FM</sub>             | 1      | А     |
| Input                   | Reverse voltage                           | $V_{R}$                     | 6      | V     |
|                         | Power dissipation (T <sub>A</sub> = 25°C) | D                           | 100    | mW    |
|                         | Derating factor (above 100°C)             | P <sub>D</sub> —            | 3.8    | mW/°C |
|                         | Collector-Emitter voltage                 | $V_{\sf CEO}$               | 80     | V     |
|                         | Collector-Base voltage                    | $V_{CBO}$                   | 80     | V     |
| Output                  | Emitter-Collector voltage                 | V <sub>ECO</sub>            | 7      | V     |
|                         | Emitter-Base voltage                      | $V_{EBO}$                   | 7      | V     |
|                         | Power dissipation (T <sub>A</sub> = 25°C) | D                           | 150    | mW    |
|                         | Derating factor (above 100°C)             | P <sub>C</sub> —            | 9.0    | mW/°C |
| Total Power Dissipation |   | P <sub>TOT</sub>            | 200    | mW    |
| Isolation Voltage*1     |   | V <sub>ISO</sub>            | 5000   | V rms |
| Operating Temperature   |   | T <sub>OPR</sub> -55 to 110 |        | °C    |
| Storage Temperature     |   | T <sub>STG</sub> -55 to 125 |        | °C    |
| Soldering Temperature*2 |   | T <sub>SOL</sub>            | 260    | °C    |

#### Notes:

<sup>\*1</sup> AC for 1 minute, R.H.=  $40 \sim 60\%$  R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

<sup>\*2</sup> For 10 seconds



# Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

| Parameter         | Symbol          | Min. | Тур. | Max. | Unit | Condition             |
|-------------------|-----------------|------|------|------|------|-----------------------|
| Forward voltage   | $V_{F}$         | -    | 1.2  | 1.5  | V    | I <sub>F</sub> = 10mA |
| Reverse current   | $I_{R}$         | -    | -    | 10   | μΑ   | V <sub>R</sub> = 6V   |
| Input capacitance | C <sub>in</sub> | -    | 30   | -    | pF   | V = 0, f = 1MHz       |

Output

| Parameter                             |  | Symbol             | Min | Тур. | Max. | Unit | Condition                     |
|---------------------------------------|--|--------------------|-----|------|------|------|-------------------------------|
| Collector-Base dark current           |  | $I_{CBO}$          | -   | -    | 20   | nA   | V <sub>CB</sub> = 10V         |
| Collector-<br>Emitter<br>dark current | 4N2X<br>H11AX                          | - loso -           | -   | -    | 50   | - nA | V <sub>CE</sub> = 10V, IF=0mA |
|                                       | 4N3X                                   | – I <sub>CEO</sub> | -   | -    | 50   | 10.0 | V <sub>CE</sub> = 60V, IF=0mA |
|                                       | Collector-Emitter<br>breakdown voltage |                    | 80  | -    | -    | V    | I <sub>c</sub> =1mA           |
| Collector-Base<br>breakdown voltage   |  | BV <sub>CBO</sub>  | 80  | -    | -    | V    | I <sub>C</sub> =0.1mA         |
| Emitter-Collector breakdown voltage   |  | $BV_{ECO}$         | 7   | -    | -    | V    | I <sub>E</sub> =0.1mA         |
| Emitter-Base<br>breakdown voltage     |  | $BV_{EBO}$         | 7   | -    | -    | V    | I <sub>E</sub> =0.1mA         |
| Collector-Emitter capacitance         |  | $C_CE$             | -   | 8    | -    | pF   | VCE=0V, f=1MHz                |

<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C



# **Transfer Characteristics**

| Parameter                    |   | Symbol               | Min              | Тур. | Max. | Unit | Condition   |  |
|------------------------------|---|----------------------|------------------|------|------|------|---|--|
| Current<br>Transfer<br>ratio | 4N35, 4N36,<br>4N37   | CTR                  | 100              | -    | -    |      |   |  |
|                              | H11A1   |                      | 50               | -    | -    | · %  |   |  |
|                              | H11A5   |                      | 30               | -    | -    |      | $I_F = \pm 10$ mA , $V_{CE} = 10$ V                               |  |
|                              | 4N25, 4N26,<br>4N38,<br>H11A2, H11A3                                |                      | 20               | -    | -    |      |   |  |
|                              | 4N27, 4N28,<br>H11A4  |                      | 10               | -    | -    |      |   |  |
|                              | 4N25, 4N26,<br>4N27, 4N28   |                      | -                | -    | 0.5  | V    | I <sub>F</sub> = 50mA, I <sub>c</sub> = 2mA                       |  |
| Collector-<br>Emitter        | 4N35, 4N36,<br>4N37   | V <sub>CE(sat)</sub> | -                | -    | 0.3  |      |   |  |
| saturation<br>voltage        | H11A1,H11A2,<br>H11A3,H11A4,<br>H11A5                               |                      | -                | -    | 0.4  |      | $I_F = 10 \text{mA}, I_c = 0.5 \text{mA}$                         |  |
|                              | 4N38  |                      | -                | -    | 1.0  |      | $I_F = 20 \text{mA}, I_C = 4 \text{mA}$                           |  |
| Isolation resistance         |   | R <sub>IO</sub>      | 10 <sup>11</sup> | -    | -    | Ω    | V <sub>IO</sub> = 500Vdc  |  |
| Input-output                 | Input-output capacitance  |                      | -                | 0.2  | -    | pF   | $V_{IO} = 0$ , $f = 1MHz$   |  |
| Turn-on time                 | 4N25, 4N26,<br>4N27, 4N28,<br>H11A1,H11A2,<br>H11A3,H11A4,<br>H11A5 | Ton                  | -                | 3    | 10   | μs   | $V_{CC}$ = 10V, $I_F$ = 10mA, $R_L$ = 100 $\Omega$ See Fig. 11    |  |
| ume                          | 4N35, 4N36,<br>4N37, 4N38   |                      | -                | 10   | 12   |      | $V_{CC} = 10V$ , $I_C = 2mA$ , $R_L = 100\Omega$ , See Fig. 11    |  |
| Turn-off<br>time             | 4N25, 4N26,<br>4N27, 4N28,<br>H11A1,H11A2,<br>H11A3,H11A4,<br>H11A5 | Toff                 | -                | 3    | 10   | μs   | $V_{CC}$ = 10V, $I_F$ = 10mA, $R_L$ = 100 $\Omega$<br>See Fig. 11 |  |
|                              | 4N35, 4N36,<br>4N37, 4N38   |                      | -                | 9    | 12   |      | $V_{CC}$ = 10V, $I_C$ = 2mA, $R_L$ = 100 $\Omega$ , See Fig. 11   |  |

<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C



# **Typical Electro-Optical Characteristics Curves**

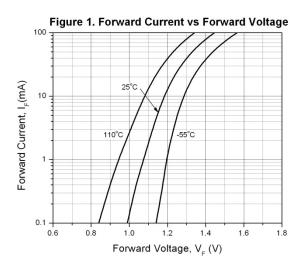


Figure 2. Current Tranfer Ratio vs Forward Current

1.2

0.8

0.8

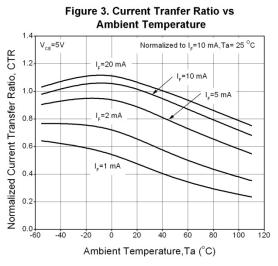
0.4

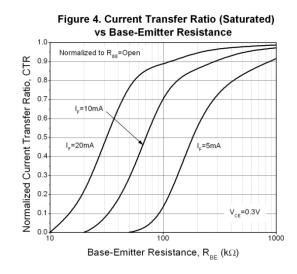
V<sub>cE</sub>=5 V

Ta=25°C

Normalized to I<sub>p</sub>=10 mA

Forward Current, I<sub>F</sub> (mA)







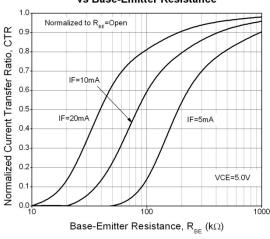
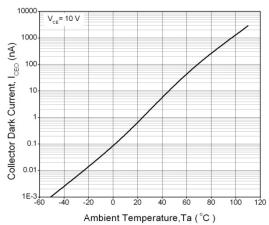
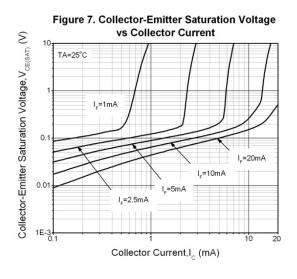
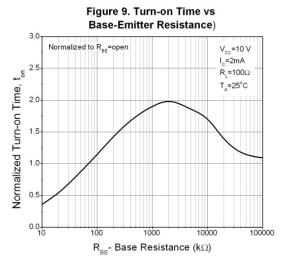
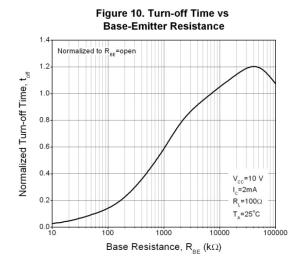


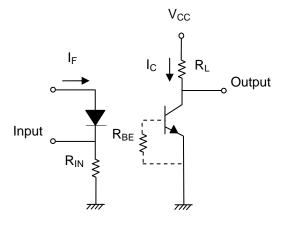
Figure 6. Dark Current vs Ambient Temperature











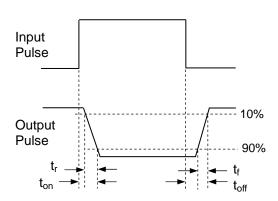


Figure 11. Switching Time Test Circuit & Waveforms



#### **Order Information**

**Part Number** 

4NXXY(Z)-V or H11AXY(Z)-V

#### Note

XX = Part no. for 4NXX series (25, 26, 27, 28, 35, 36, 37 or 38)

X = Part no. for H11AX series (1, 2, 3, 4, or 5)

Y = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB or none).

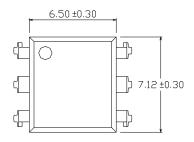
V = VDE safety (optional)

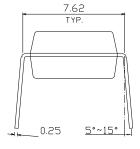
| Option  | Description   | Packing quantity    |
|---------|---|---------------------|
| None    | Standard DIP-6  | 65 units per tube   |
| М       | Wide lead bend (0.4 inch spacing)                             | 65 units per tube   |
| S (TA)  | Surface mount lead form + TA tape & reel option               | 1000 units per reel |
| S (TB)  | Surface mount lead form + TB tape & reel option               | 1000 units per reel |
| S1 (TA) | Surface mount lead form (low profile) + TA tape & reel option | 1000 units per reel |
| S1 (TB) | Surface mount lead form (low profile) + TB tape & reel option | 1000 units per reel |

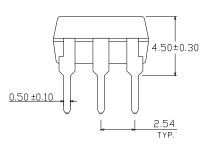


# Package Dimension (Dimensions in mm)

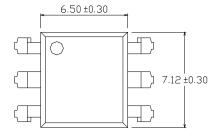
# **Standard DIP Type**

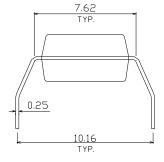


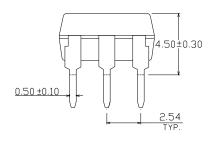




### **Option M Type**

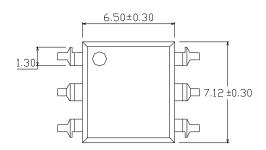


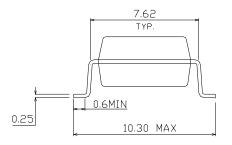


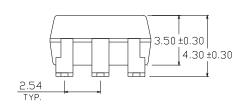




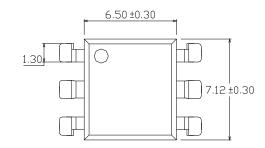
# **Option S Type**

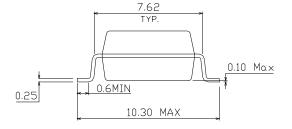


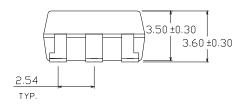




# **Option S1 Type**

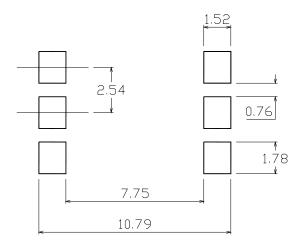




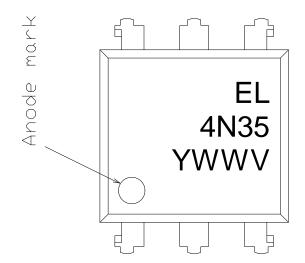




# Recommended pad layout for surface mount leadform



# **Device Marking**



#### **Notes**

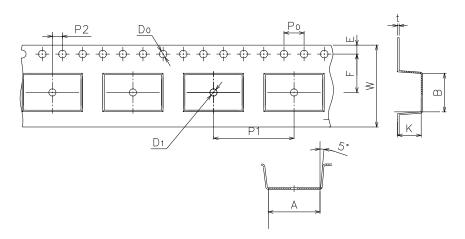
EL denotes Everlight
4N35 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



**Tape & Reel Packing Specifications** 

# Option TA Option TB Option TB Direction of feed from reel

# **Tape dimensions**



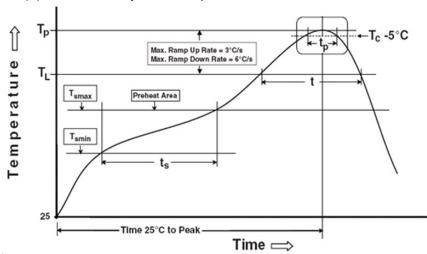
| Dimension No.  | Α        | В       | Do      | D1         | E        | F       |
|----------------|----------|---------|---------|------------|----------|---------|
| Dimension (mm) | 10.4±0.1 | 7.5±0.1 | 1.5±0.1 | 1.5+0.1/-0 | 1.75±0.1 | 7.5±0.1 |
| Dimension No.  | Ро       | P1      | P2      | t          | w        | К       |
| Dimension (mm) | 4.0±0.15 | 12±0.1  | 2.0±0.1 | 0.35±0.03  | 16.0±0.2 | 4.5±0.1 |



#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

#### **Preheat**

Temperature min  $(T_{smin})$  150 °C

Temperature max  $(T_{smax})$  200 °C

Time  $(T_{smin} \text{ to } T_{smax}) (t_s)$  60-120 s

 $\begin{array}{ll} \text{Time } (T_{smin} \text{ to } T_{smax}) \ (t_s) & 60\text{-}120 \text{ seconds} \\ \text{Average ramp-up rate } (T_{smax} \text{ to } T_p) & 3 \text{ °C/second max} \end{array}$ 

#### Other

Liquidus Temperature ( $T_L$ )

Time above Liquidus Temperature ( $t_L$ )

60-100 sec

Peak Temperature ( $T_P$ )

260°C

Time within 5 °C of Actual Peak Temperature:  $T_L$  5°C

Time within 5 °C of Actual Peak Temperature: T<sub>P</sub> - 5°C 30 s

Ramp- Down Rate from Peak Temperature 6°C /second max.

Time 25°C to peak temperature 8 minutes max.
Reflow times 3 times

•



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